# Q uantum M onte C arlo sim ulation for the spin-drag conductance of the H ubbard m odel 

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#### Abstract

In the situation of two electro-statically coupled conductors a current in one conductor may induce a current in the other one. W e will study this phenom enon, called C oulomb drag, in the H ubbard chain where the two \conductors" are given by ferm ions w ith di erent spin orientation. $W$ ith the aid of $M$ onte C arlo (MC) approach which we presented in a recent paper we calculate the T ransconductance in di erent variants of the H ubbard chain (w ith/w ithout im purity and additional [ong-ranged] interactions) for di erent llings.


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## I. INTRODUCTION

The Coulomb-drag e ect describes how two conductors (only coupled by the C oulomb force) $m$ ay in uence each other. Since the Coulom b repulsion is relatively sm all, a sizeable e ect will only arise when the two conductors are very close to each other. This condition can be $m$ et in $m$ esoscopic system $s \mid$ where $w$ ith the advent of new technologies (e.g., carbon nanotubes) the problem of C oulom b drag attracted $m$ ore and $m$ ore attention (e.g., Refs. ${ }^{1} 1$ stead of considering tw o conductors onem ay look at drag e ects between di erent ferm ion species, e.g., ferm ions with di erent spin orientation. Since ferm ions with different spins are not spatially separated, there is a large C oulom b force betw een them which can lead to all kinds of correlation e ects, e.g., a drage ect. In the last years, the interest in spin-dependent transport increased. O ne key problem is the generation of a spin-polarized current, i.e., a current where only ferm ions with one of the two spin orientations ow. In this context it is im portant to keep in $m$ ind that the spin-polarized current $m$ ay a ect the ferm ions w ith the opposite spin orientation. H ence, the drage ect m ay play here a crucialrole even though it is experim entally not directly accessible. (T his is because the driving potentials are in general not spin dependent.)

For this \spin-drag" problem the trans-resistivity of higher dim ensionalsystem shas been investigated in previous publications, e.g., using the $B a \nmid z m$ ann equation ${ }^{51}$ or the random-phase approxim ation ${ }^{51}$ In this paper we focus on the Transconductance for the $H$ ubbard $m$ odel. W hile most authors used, a bosonization approach to
 study of the T ransconductance, a M onte C arlo m ethod which we introduced in a recent paper? $T$ he strategy we followed there was to $m$ ap our ferm ion system via the Jordan W igner transform ation to a spin system which can be analyzed by e cient though standard M onte C arlo techniques. W ewill now extend this $m$ ethod to the onedim ensional $\mathrm{H} u b b a r d \mathrm{~m}$ odel concentrating on the question how a spin-polarized current (driven by a voltage drop which is assum ed to be spin dependent) a ects the
ferm ions with opposite spin orientation.
In the Section II we present the $m$ odel and give som e gentral de nitions for the spin-drag problem. The Sec. III contains the technical details on the sub ject, of the M C simulations. The M C m ethod of our choioe ${ }^{141101}$ was a variant of the Stochastic Series Expansion (SSE) as introduced in Refs . investigation of the onedim ensionaly ubbard $m$ odel $1^{191} \mathbf{N}^{161}$

In the follow ing Sec. 'IV̄ À' we present our results for the standard $H$ ubbard $m$ odel and com pare $w$ th analytical predictions from bosonization theory., To obtain a spin-polarized current we add in Sec. IV Bı an im purity to the system, which acts like a com bination of a onesite chem icalpotential and a one-site $m$ agnetic eld. W e show that such a \m agnetic" im purity can produce the desired spin-polarized current.

The H ubbard $m$ odel can also be $m$ apped to a spinlessferm ion ladder. H ence, our resultsm ay also describe that situation, but there one $m$ ight argue that the very speci c m odeling of the Coulomb (on-site) interaction in the $H$ ubbard $m$ odel is unrealistic (and $m$ ay di er from other approaches, e.g., Refs.' ${ }^{\prime 2}$ cuss two variants (w ith additional interaction term $s$ ) of ourm odel. F irst, we w illdiscuss in Sec. IV Ci a situation, where ferm ionsw ith di erent spins live on di erent sites. The fiull system has the geom etry of zig-zag chain. Second, we show in the appendix that a spin-polarized interaction leads to equalC is- and $T$ ransconductance. $T$ his is sim ilar to the \absolute" drag result found, e.g., in Ref.育。
II. DEFINITION OF THESP $\mathbb{N}$ DRAG $\mathbb{I N}$ THE HUBBARD MODEL

Our model H am iltonian is the standard H ubbard m odel (w ith N sites or atom s )

$$
\begin{align*}
& \mathrm{n} \text {; } \mathrm{n} \tag{1}
\end{align*}
$$

where $n_{n}$; is the occupation num ber of ferm ions with spin at site $n$, and $C_{n}^{(y)}$; is the corresponding annihilation (creation) operator. To perform our transport calculations, we will use the approach from Ref. 'İ. Since the hopping term does not connect ferm ions with di erent spins, it is natural to consider current and potential operators for each spin orientation separately. Follow ing Ref. ' 1 charge unit and $x$ being the position of the voltage drop)

$$
P_{x}^{\#}=e_{n>x}^{X} n_{n ; \# ;} \quad P_{x}^{\prime \prime}=e_{n>x}^{X} n_{n ; "}:
$$

The conductance (of a spinless-ferm ion chain) is the linear response of one potential operator to another; therefore the explicit form of the current operators is not needed here ${ }^{\text {gl' }}$ ' A s we have two potentials, we can de ne four transport quantities (conductances) $g_{i j}$ which describe the (linear) response of $P^{i}$ to $P^{j}$ where i;j $2 f " ; \#$ $g$. Further details on how to evaluate the $g_{i j}$ 's are to be found in section

For them om entwew illdiscuss only sym $m$ etricm odels, i.e., we have spin-rotational invariance (the only asym $m$ etric $m$ odel that we w ill discuss appears in Sec. $\mathbb{I N} \mathrm{B}_{\mathrm{d}}^{1}$ ); thus, weend up with only tw o distinct quantities. W e call $g_{c}:=g_{\# \#}=g_{" n}$ the C isconductance and $g_{t}:=g_{\# "}=g_{" \#}$ the T ransconductance.

The nam ing conventions com efrom the physical interpretation of these coe cientswhich is the follow ing: Ifwe sw itch on at a certain tim e a (supposedly) spin-polarized potential which acts only on spin-up ferm ions (i.e., we add a tim e-dependent perturbation of the form

$$
V P^{"} \quad(t)
$$

$w$ ith $V$ being the voltage am plitude and the $H$ eavysidestep function) we will nd a current of spin-up ferm ions

$$
I^{\prime \prime}=g_{c} V:
$$

$T$ his is the drive current govemed by the C isconductance, but there will also be a current of spin-dow $n$ ferm ions

$$
I^{\#}=g_{t} V \text {; }
$$

the drag current (govemed by the Transconductance). $T$ he latter $m$ ay be nonzero, even though the spin-dow $n$ ferm ions do not feel the applied potential.
$T$ he situation of a nonvanishing $T$ ransconductance (or drag current) is called C oulom b drag. This problem has been studied, e.g., for coupled spinless-ferm ion system s by bosonization in Refs. '11"n' turbation theory in Ref. ${ }_{1}$

Norm ally, (since spin-polarized potentials are not available) one is only interested in the (fill) conductance of the $H$ ubbard $m$ odel, where both ferm ion species feel the sam e potential, and the fiull current is the sum of the currents of the spin-up and spin-dow $n$ ferm ions. As is straightforw ard to see, the C is- and T ransconductance give us directly the conductance of the $H$ ubbard $m$ odel via the relation $g_{H \text { ubbard }}=2\left(g_{c}+g_{t}\right)$.
III. DESCRIPTION OF THEMONTECARLO METHOD

B efore starting with M onte C arlo we have to cast our H am iltonian in a convenient form .
Using the Jordan-w igner transform the Hubbard $m$ odel can be $m$ apped to a spin ladder. To each occupation operator we introduce a spin operator, i.e., we replace $n_{n} ; "!S_{2 n}^{z}+1=2$ and $n_{n} ; \#!S_{2 n+1}^{z}+1=2$. If we express the $H$ ubbard $H$ am iltonian $w$ ith those new operators we obtain the follow ing spin ladder (w ith 2N sites):

$$
\begin{align*}
H & =X \quad J_{x}\left(S_{n}^{+} S_{n+2}+S_{n} S_{n+2}^{+}\right)=2+J_{z} S_{n}^{z} S_{n+1}^{z}+B S_{n}^{z} \\
& +{ }^{\mathrm{X}} \quad \\
& U S_{2 n}^{z} S_{2 n+1}^{z}+U^{0} S_{2 n+1}^{z} S_{2 n+2}^{z} ;
\end{align*}
$$

where the sites with even number represent spin-up ferm ions and the sites $w$ th odd numbers, spin-down ferm ions. (For the Hubbard model one has to put $J_{z}=0=U^{0}$. These param eters are used to model the spin-polarized interaction from the appendix and the zigzag chain from Sec. $\bar{I} \bar{I} \bar{C} \bar{\prime}$; see bottom half off ig. $\overline{111}$. T he sites $2 n$ and $2 n+1$ in the ladder represent therefore one atom of the $H$ ubbard $m$ odel and interact via an Ising interaction representing the C oulom b force (see Fig. '1지) . $T$ he hopping am plitudes satisfy $J_{\underline{\underline{x}}}=2 t$, and the strength of the $m$ agnetic eld B in Eq. ${ }^{\prime}(\underset{2}{ })$ is obtained from the chem icalpotential via the relation $B=U=2+U^{0}=2$ $H$ alf lling corresponds therefore to $B=0$. The two potential operators $\mathrm{P}_{\mathrm{x}}$; ${ }^{\#}$ introduced in the previous section can be related to potential operators for the two chains (e being the charge unit)

$$
P_{x}^{\#}=e_{n>x}^{X} S_{2 n+1}^{z} ; \quad P_{x}^{\prime \prime}=e_{n>x}^{X} S_{2 n}^{z}:
$$

T hen wem ay obtain the four conductances $g_{i j}$ introduced in the previous section by computing ( $i ; j 2 \mathrm{f} \# ; \mathrm{F}$ )

$$
\begin{equation*}
g_{i j}\left(!_{M}\right)=\quad!_{M}=\sim \sim \sim\left(\operatorname{Cos}_{M} \quad\right) h P_{x}^{i} P_{Y}^{j}(i) i d \tag{3}
\end{equation*}
$$

at the $M$ atsubara frequencies $!_{M}=2 M(\sim){ }^{1}$; M 2 N , and then extrapolating to ! $=0$. (The extrapolated value should not depend on $x$ or $y{ }^{12}$ W e chose $\mathrm{x}=\mathrm{N}=2=\mathrm{y}$ 1.) For the extrapolation from $\mathrm{g}\left(!_{\mathrm{M}}\right)$ to $g(!=0)$ we will use a quadratic $t$ from the rst three $M$ atsubara frequencies. Wew illuse open (O BC's) instead of periodic boundary conditions (P B C's).] Since the H am iltonian contains H eisenberg-like interactions as well as Ising-like interactions, it is advantageous to use the Stochastic C luster Series Expansion (SC SE) introduced in Ref. 110. For the Hubbard m odel the SC SE gives essentially the sam e update schem e as the one used in Ref. $\overline{1}$ G. W e will explain it now shortly.

Foplow ing R ef.ig we split the H am iltonian according to $\mathrm{H}=\mathrm{h}_{2} \mathrm{~h}$ h, but this tim e into four-sites clusters, called


FIG .1: Them odelH am iltonian that w illbe discussed in this paper. Solid lines indicate a full H eisenberg-like interaction betw een the sites; dashed lines stand for sites coupled only by a $z-z$ term (Ising-like interaction). The upper part is for $U^{0}=0$. The lower for $U^{0}=U$. ( $O$ ther values of $U^{0}$ are not considered.) A plaquette as used in the M C scheme is indicated by boldface lines.
plaquettes (see Fig. ${ }^{\text {I }}$ (11) $)$. The follow ing operators belong to the plaquette $P$ (containing interactions betw een the sites $2 n, 2 n+1,2 n+2$, and $2 n+3$ ):

$$
\begin{aligned}
h_{P}^{(1)} & =J_{x} S_{2 n}^{+} S_{2 n+2}=2 \quad \\
h_{P}^{(3)} & =J_{\mathrm{x}}^{(2)} S_{2 n+1}^{+} S_{2 n+3}=2 \quad J_{x} S_{2 n} S_{2 n+2}^{+}=2 \\
h_{P}^{(5)} & =C+U=2 S_{2 n}^{z} S_{2 n+1}^{z}+U=2 S_{2 n+2}^{z} S_{2 n+3}^{z}+ \\
& +U^{0} S_{2 n+1}^{z} S_{2 n+2}^{z}+J_{z} S_{2 n+1}^{z} S_{2 n+3}^{z}+J_{z} S_{2 n}^{z} S_{2 n+2}^{z} \\
& +B=2\left(S_{2 n}^{z}+S_{2 n+1}^{z}+S_{2 n+2}^{z}+S_{2 n+3}^{z}\right):
\end{aligned}
$$

The set $h$ consists of $a l l h_{P}^{(t)}$ for all plaquettes $P$ and all $t=1 ;::: ; 5$.

The heart of the SC SE program is the so called loop update, where a spin ip of a subset (loop) of all spin variables is proposed. Since the sites w ith even and odd num bers form two chains, which are only coupled by a $z-z$ interaction term, we nd that the set of spin variables that w illbe ipped in the loop update belongs entirely to one of the chains. Therefore, we can view the new algorithm as $m$ aking loop updates for each chain separately. D uring a loop update for one chain the spin variables of the other chain rem ain $x e d$. The consequence of this is that, if we update, e.g., the even chain, then operators $w$ th superscript $i=3 ; 4$ can be neglected (are irrelevant for the loop construction), and the coupling term $s$ (betw een the chains) reduce to $m$ agnetic eld term $s$ (for the even chain).

It is how ever advantageous to consider another variant of the loop update. The construction is sim ilar to the rst variant, but now we propose spin ips for both chains, i.e., the spin variables belonging to sites $2 n$ and $2 n+1$ are ipped sim ultaneously. This $m$ ay be view ed as a construction of tw o parallel loops| one for each chain. Since the tw o loops m ust be parallel, the num ber of possible transitions betw een di erent plaquette states_is reduced. This m ay lead to a less e cient algorithm in but one should note that this parallel-loop update becom es determ inistic for the case of $B=0$ and hence enhances the e ciency of the algorithm (at least for this situation)
considerably.
IV. NUMERICALRESULTS
A. Transconductance in the $H$ ubbard model

1. C om parison $w$ ith the $H$ ubbard $m$ odel

In bosonization theory the $H$ ubbard $m$ odel is described by tw o boson elds "; ; representing the degrees of freedom ofdi erent spin orientations. The current operators for the spin sectors are then given by $J_{n ; \#} / @_{x}{ }_{n ; \#} \eta_{1}$ The conductance fan be w ritten in the form of a currentcurrent correlato $r^{\prime \prime}$ and $m$ ay be evaluated in term s of the Luttinger-liquid param eters K ; of the charge and spin eld $==(\|, \#)=\overline{2}$. The result is (using the linearity of the correlator and the results from $R$ ef. 1$]_{1}$ )

$$
\begin{equation*}
g_{c}=\frac{1}{2}(k+K) \quad g_{t}=\frac{1}{2}(k \quad K): \tag{4}
\end{equation*}
$$

W hen $=\mathrm{U}=2 \mathrm{we}$ are at half lling, where Umklapp processes are responsible for a gap in the system $1_{1}^{181}$ The (charge) gap (U) depends on the $H$ ubbard repulsion $U$ and is nite for all $U$.

## 2. N um erical sim ulations

W e present now M onte C arlo results for the $T$ ransconductance in the $H$ ubbard $m$ odel Eq. ( $\overline{1}$ ) (or Eq. ( $\overline{\text { Z }}$ ) for $\left.\mathrm{U}^{0}=0\right]$.

W e perform ed sim ulations for two di erent chem ical potentials: First, $=U=2$ corresponding to half lling and second $=0$. In the latter case the system is no longer at half lling, but has a U-dependent lling, which is show in $F$ ig. $111_{-1}^{\prime}$ of the appendix (in the large-U lim it the system reaches quarter lling).
$W$ e show $g_{c}$ and $g_{t}$ as a function of $U$ for the two different 's in $F$ ig. ${ }^{\prime}$ r. The gure show $s$ that the $C$ oulomb drag is very sensitive to a change in chem icalpotential.

Let us rst look at the half- led case ( $F$ ig in in . If U is very large the Coulomb repulsion acts as an e ective projection to those con gurations satisfying $P^{\#}=P^{\prime \prime}$. This implies that $g_{c}+g_{t}$ ! 0 as $U$ ! 1 . This contemplation is in accordanœe with Fig. W e should actually expect from Eq. (4, $\overline{1}$ ) that for $T=0$ we have $g_{c}+g_{t}=K=0$ because of the charge gap (U) $>0$ for all U > 0 (cf. Ref.idg). This should lead to a discontinuous jump at $U=0$, because $w$ thout the $C$ oulom b force evidently $g_{t}=0$ and $g_{c}$ is the conductance of uncoupled spinless-ferm ion chains from Ref. $1 \xi_{1}$. Here we em phasize that ourm ethod is a nite-tem perature m ethod, which $m$ eans that the conductances calculated by us interpolate sm oothly between the values for $\mathrm{U}=0$ and $\mathrm{U}=1 . \mathrm{T}$ he crossover is expected to take place at that interaction value $U_{T}$ which satis es $\left(U_{T}\right)=k_{B} T$. It is therefore interesting to see how $g_{c, t}$ scale with tem perature. H ow ever, our m ethod gives only access to the


FIG. 2: C is and Transconductance (led/em pty sym bols) of the $H$ ubbard $m$ odel as a function of $U$ for two di erent 's (200 sites, $T=0: 02 t=k_{B}$, OBC's, $210^{5} \mathrm{M} \mathrm{C}$ sweeps.) The (solid) arrow indicates the $U_{T}$ for which the charge gap (present at half lling) satis es ( U т ) $=\mathrm{k}_{\mathrm{B}} \mathrm{T}$. (The dotted arrow show $\mathrm{U}_{\mathrm{T}=2}$ where ( $\mathrm{U}_{\mathrm{T}=2}$ ) $=\mathrm{k}_{\mathrm{B}} \mathrm{T}=2$ for com parison.)
 for only two di erent tem peratures, $\mathrm{k}_{\mathrm{B}} \mathrm{T}=0: 01 \mathrm{t}$ and $k_{B} T=0: 02 t$. In the two subsequent sim ulations for the C is//T ransconductance we did not nd any di erence at all. This im plies only a w eak tem perature dependence (at low $T$ ) for the interaction $U_{T}$ which govems the crossover. Since ( U ) isknown from analyticalresults, ${ }^{\text {in }}$ we can calculate the two crossover interactions| de ned by $\left(\mathrm{U}_{0: 02}\right)=0: 02 \mathrm{t}$ and $\left(\mathrm{U}_{0: 01}\right)=0: 01 \mathrm{t} \mid$ nding that $\mathrm{U}_{0: 02} \quad 1: 25 \mathrm{t}$ and $\mathrm{U}_{0: 01} \quad 1: 12 \mathrm{t}$ do not di ermuch, as expected (they are also both indicated by arrow s in Fig. (27).

A nother im portant consequence of $g_{c}+g_{t}!0$ is that the signs of the $C$ is- and $T$ ransconductance are opposite or| in term softhe spin-up and spin-dow $n$ currents| that the induced drag current ows in the opposite direction of the drive current ${ }^{20}$

Now we will tum to the spin sector. W e have $\mathrm{K} \quad \bar{\equiv}$, 1 by spin-rotational invariance of the H ubbard $m$ odel ${ }^{8!}$ im plying [see Eq. ( $\overline{4}$ ) $)] g_{c} \quad g_{t}=1$ for all $U$ which is very well satis ed by Fig

Putting the tw o results for $g_{c} \quad g_{t}$ together, we obtain $g_{c}=0: 5 \mathrm{e}^{2}=\mathrm{h}=g_{t}$ valid at high $U$. This large-U lim it of $g_{c} m$ ay also be com puted in second-order perturbation theory. In this approxim ation the $H$ ubbard $m$ odel can be $m$ apped to a $H$ eisenberg $m$ odel. The operator [on the
 which is e ectively equal to $P_{x}^{\#}$, is identi ed with the operator (on the $H$ ibert space of the e ective $H$ eisenberg m odel) $\mathrm{P}_{\mathrm{x}}=\mathrm{n}_{\mathrm{n}>\mathrm{x}} \mathrm{T}_{\mathrm{n}}^{\mathrm{z}} \cdot\left[\mathrm{T}_{\mathrm{n}}^{\mathrm{z}}=\left(\mathrm{n}_{\mathrm{n}} ;{ }^{\prime \prime} \quad \mathrm{n}_{\mathrm{n}} ; \#\right)=2\right.$ is the spin operator for ferm ions; here denoted by $T$ to avoid confusion w ith the spin operators appearing in Sec. IIIT.] A pplying the results from Ref. 1 reduces then to the com putation of the spin conductance of the $H$ eisenberg $m$ odel, which equals one half in units $e^{2}=h$.


F IG . 3: Them odelH am iltonian $w$ ith an im purity at site $N=2$ for $N=6$ in the spin ladder representation from the upper half of $F$ ig. II (for $U^{0}=0$ ). The site on which the im purity potential acts is en circled.

In the case of zero (again $F$ ig. $\overline{2}$ ) where the system is aw ay from half lling there is no charge gap. H ence, $K$ is nite, and so Eq. $\cdot\left(\frac{1}{1}\right)$ tells us that $q+g_{t}=K$ does not decay w ith U. H ere we note that $g_{c}+g_{t}$ agrees (w ithin error bars) $w$ th the values for $K$ available in Ref. 1 W e still have $\mathrm{K}=1$, which leads to $g_{c} g_{t}=1$ for all $U$ (again very well satis ed by the gure).

Finally, we consider the large-U lim it. Inserting K $(U=1)=0: 5$ and $K \quad 1$ from Ref. 1 $\left(\underline{4}^{-1}\right) y$ ields $g_{c}=0: 75$ and $g_{t}=0: 25$ (units $e^{2}=\bar{h}$ ). These results are in accordance w th the gure. (N ote that the statistical error increases $w$ th $U$ such that we cannot com pute $g(U)$ for su ciently high $U$ in order to extract the large-U lim it accurately.)

## B . M agnetic Im purity

In this subsection we will study the in uence of an im purity. Them odeling of the im purity follow s Ref. ${ }^{1} 1$ but for the spin-drag problem it is natural to consider a spin-dependent im purity, as we will do here. W e extend therefore our H am iltonian in the follow ing way

$$
\mathrm{H}=\mathrm{H}_{\mathrm{Hubb}}+\mathrm{B}_{\mathrm{Im} \mathrm{p}} \mathrm{n}_{\mathrm{N}=2 ; " ;} ;
$$

i.e., we introduce an (im purity) potential at exactly one central site (which acts only on one spin orientation, see


F ig. 'IT1' show S C isconductances and Transconductances as a function of the im purity potential $B_{\text {Im }}$ at half $l-$ ing. (T he exam ple is chosen such that the Transconductance in the unperturbed system is relatively large.) The conductance of the $H$ eisenberg chain w ith one im purity, which is the largeU lim it of $g_{c}$, is given for com parison.

A though the tw o C isconductances, $g^{\prime \prime}$ " and $g_{\# \#}$, could in principle di er (the $m$ odel is now asym $m$ etric) they do not in the case of half lling| at least within error bars. B oth C isconductance and T ransconductance go $m$ ore or less linearly $\mid$ to zero as the im purity strength increases.
$W$ e note that $w$ ithin error bars $g_{c}=g_{t}$ such that the full conductance of the system

$$
g=2\left(g_{c}+g_{t}\right)
$$



FIG. 4: The C is- and Transconductance (led/em pty sym bols) as a function of the im purity strength $B_{\text {Im }} p$ at half lling. The im purity acts on spin-up ferm ions. N ote that the C isconductance for the spin-up ferm ions g" " (triangle up) $m$ ight di er from the one of the spin-down ferm ions $g_{\# \#}$ (triangle dow $n$ ). The tw o T ransconductances are the sam e . The conductance of an xxx (H eisenberg) chain with one im purity (which should coincide with the large-U lim it of the C isconductance) is given for com parison. ( $=U=2, U=2 t$, $\mathrm{N}=192$ sites, $\mathrm{T}=0: 02 \mathrm{t}=\mathrm{k}_{\mathrm{B}}$.)


F IG . 5: The C is- and Transconductance (lled/em pty sym bols) as a function of the im purity strength $B_{\text {Im }}$ p in the $\mathrm{H} u \mathrm{bbard} \mathrm{m}$ odel aw ay from half lling. The impurity acts on spin-up ferm ions. $N$ ote that the C isconductance for the spin-up ferm ions $g_{"} "$ (triangle up) di ers from the one of the spin-dow $n$ ferm ions $g_{\# \#}$ (triangle down). The two Transconductances are the same. ( $=0, \mathrm{U}=4 \mathrm{t}, \mathrm{N}=192$ sites, $\mathrm{T}=0: 02 \mathrm{t}=\mathrm{k}_{\mathrm{B}}$. .)
rem ains zero after insertion of the im purity. Further$m$ ore, investigations $w$ ith our $m$ ethod at di erent tem peratures nd no sizeable T -dependence.

In the case of zero chem ical potential, $=0$, we nd a
 particularly interesting since this nding im plies a spinpolarized current. If we assum e a (spin-independent) driving potential of the form

$$
V\left(P^{\prime \prime}+P^{\#}\right)
$$

( $V$ being the voltage am plitude), then the current is
$I=I^{\prime \prime}+I^{\#} ; \quad I^{\prime \prime}=\left(g_{"}+g_{" \#}\right) V \quad I^{\#}=\left(g_{\#}+g_{\# \#}\right) V:$
$T$ he average spin of a ferm ion in the current is therefore (using $g_{\#}=g_{" \#}=g_{t}$ )

$$
S=\frac{I^{"} I^{\#}}{2 I}=\frac{g_{" n} g_{\# \#}}{2\left(g_{n "}+g_{\# \#}+2 g_{t}\right)}
$$

di enent from zero (see F ig ${ }_{2}^{-} \mathrm{F}$ ).


F IG . 6: The negative average spin polarization (S) of the induced current as a function of the im purity strength $B_{\text {Im }}$ p in the $H$ ubbard $m$ odel aw ay from half lling. The im purity acts on spin-up ferm ions. The_dashed curve is obtained by tting $g_{"} ", g_{\# \#}$ and $g_{t}$ in Fig. 'İ w ith an exponential ansatz and substituting these ts into the formula for $S .(=0$, $\mathrm{U}=4 \mathrm{t}, \mathrm{N}=192$ sites, $\mathrm{T}=0: 02 \mathrm{t}=\mathrm{k}_{\mathrm{B}}$.)

An interesting problem is the question whether for $=0$ the C isconductance in the pure (spin-dow $n$ ) sector $g_{\# \#}$ survives or not when we increase $B_{\text {Im }}$ to in nity. N ote that a nite $9 \#$ w ould im ply a total spin polarization, i.e., $S=1=2$. The lim it $\mathrm{B}_{\mathrm{Im} p}$ ! 1 of $\mathrm{g}_{\# \#}$ cannot be taken directly (because of problem $s$ w ith the M C sim ulation), but here we note that there is another way to m odel the im purity. Instead of applying a localm agnetic eld on one site, one can introduce a w eak link, i.e., decrease the hopping am plitude for spin-up ferm ions betw een the sites $N=2$ and $N=2+1$ from the in itialvalue to $t_{\text {Im } p}^{\prime \prime}$. These tw o variants of im purities behave sim ilarly $\eta_{1}^{\eta_{1}^{\prime}}$ W e com puted the C isconductance for the una ected spin orientation for the $m$ odel $w$ th $t_{\text {Im } p}^{\prime \prime}=0$ (corresponds to $B_{\text {Imp }}=1$ ) at $=0, U=4 t, N=200$ sites. $W$ e nd a value of about $[0: 79 \quad 0: 03] \mathrm{e}^{2}=\mathrm{h}$.

The di erent behavior of the $C$ isconductance in the (una ected) spin-down sector at half lling and aw ay from half lling $m$ ay be explained as follows: Suppose $B_{\text {Im } p}$ and $U$ are large. The ect of the $B_{\text {Im }} p$ term on the ferm ions is that it forbids occupation of the im purity site for one of the two ferm ion species (in our case spin-up ferm ions). At half lling a spin-up ferm ion can hop only from one site to another by exchanging the site $w$ th a spin-dow $n$ ferm ion (there are no em pty sites),
i.e., sim ultaneously w ith the spin-up a spin-dow $n$ ferm ion m ust hop in the opposite direction et vioe versa (im plying $\left.g_{c}=g_{t}\right)$. A ferm ion of a certain spin index can then only pass the im purity site if accom panied by a ferm ion of opposite spin (which m oves in the opposite direction). Since the impurity site is forbidden for one of the two ferm ion species, no ferm ion can pass the im purity site, and both C isconductances m ust go to zero.

Away from half lling the hopping of an spin-up ferm ion does not necessarily require the hopping of a spin-down ferm ion (the spin-up ferm ion can hop to an em pty site) and hence the im purity a ects only one of the two C isconductances.

## C. Z ig-zag chain

So far we have dealt with a system of two ferm ion species, where the two species reside on the sam e set of sites. In contrast to this, the bosonization approaches considered mostly system s of two coupled spinless-ferm ion conductors. W e can com pare our results $w$ th that situation, if we intenpret the $H$ ubbard model as a spinless-ferm ion ladder. H ere one assum es that each ferm ion species lives on a di erent conductor [i.e., the tw o indices ( $n ; "$ ) and ( $n ; \#$ ) are supposed to label (spatially) di erent sites; com pare Secin IIT and upper half of F ig. ${ }_{1}^{1111]}$. B ut one should note that for this case the param eter U should be sm all (since the distance betw een separated conductors is large) and the C oulom b interaction should be long-ranged (not on-site as in the $\mathrm{H} u b b a r d \mathrm{~m}$ odel). H ence we are led to the question how a variation in the interaction term modi es our results.

To address this question we add a new interaction term to the $H$ ubbard $m$ odel

$$
\mathrm{H}=\mathrm{H}_{\mathrm{Hubb}}+\mathrm{U}_{\mathrm{n}}^{\mathrm{X}} \mathrm{n}_{\mathrm{n} ; \#} \mathrm{n}_{\mathrm{n}+1 ; ":} \text { : }
$$

This H am iltonian corresponds to Eq. (Z) w ith $\mathrm{U}^{0}=\mathrm{U}$. O ne can justify introducing this new interaction term if the ferm ion species live on di erent sites w here each spindown site ( $n ; \#$ ) lies betw een two spin-up sites, ( $n$;") and ( $n+1 ; "$ ). This $m$ odel has therefore the geom etry of a frustrated zig-zag chain as depicted in the low er half of Fig. ${ }^{\overline{1} 11}$.

O ne should note that this system has a total of 2 N sites, $N$ sites for each ferm ion species. A though it would be useful to adopt the notion of a system with two coupled (spinless-ferm ion) chains, we will keep here the notation of a system of spinfull ferm ions.]
$T$ he results for the spin drag in this $m$ odel are show $n$ in Fig. $\overline{1}_{1}$, . W e discuss again two chem icalpotentials: one is $=U$ im plying half lling, the other is again $=0$. In the latter case the ( $m$ ean) occupation num ber per site $n$ is di erent from one half (the occupation at half lling) and depends on $U$. It is shown in $F$ ig. $\overline{1}_{1}^{1}$.

O ne sees in F ig. ${ }^{1} 7$ 7, that $\mathrm{g}_{\mathrm{c}, \mathrm{t}}$ jgrow w ith the strength of the interaction. T his $m$ ay be explained as follow s: $F$ irst,


F IG . 7: C is- and Transconductance ( lled/em pty sym bols) of the zig-zag chain for tw o m agnetic elds_( 120 sites per ferm ion species, $T=0: 02 t=\mathrm{k}_{\mathrm{B}}, \mathrm{U}^{0}=\mathrm{U}$ in Eq . (i) , OBC's, $210^{5} \mathrm{MC}$ sw eeps.)
the C oulomb interaction $m$ ediates an attractive nearestneighbor interaction for ferm ions $w$ th equalspin orientation (this is a consequence of the frustration). Therefore, in a simple approxim ation the only e ect of the C oulom b interaction is to renorm alize the Luttinger-liquid param eters for the two spin sectors $K$ ";\# . Since the Luttinger param eter for a spinless-ferm ion chain increases $w$ ith the strength of the attraction, 81 we expect that K " ; increases as $U$ increases. Since $K$ ";\# gives the conductance of one spin sectort ${ }^{17}$. (w hich is essentially the C isconductance) we have that $g_{c}$ increases $w$ ith $U$.

O nem ay also infer from the gure that the dependence of $g_{c ; t}$ on a chem ical-potentialshift is weak. W ithin error bars $g_{c}$ decreases only slightly upon shifting aw ay from half lling.

O ne should note that in the lim it $U=1$ the ground state is a spin-polarized con guration (see Fig, íp). For
$=U$ this $m$ eans that all conductances are zero in the large-U lim it, for one spin sector is em pty and the other, com pletely led. In contrast to this, for $=0$ one of the two spin sectors $m$ ay rem ain conducting. The crossover to the ordered state occurs at values of $U$ larger than 3t which $m$ ay be seen by sim ulating and com paring the occupation number for di erent states. For $=0$ the di erenpe in occupation (between the two spin sectors) $n=h j{ }_{n}\left(n_{n} ; " \quad n_{n} ; \#\right) \ddot{\mu}=(2 N)$ is shown in $F i g$. $\overline{1}$; for $=\mathrm{U}$ it is zero w thin error bars as long as U 3t. We conclude that for the values of $U$ considered in $F$ ig. $1, \overline{1} 1$ the tw o spin sectors have approxim ately the sam e lling.

## V. CONCLUSION

In this paper we discussed the spin drag for the $\mathrm{H} u b-$ bard model at zero tem perature. $W$ e found that the Transconductance is negative at half lling the Umklapp even enforces $g_{c}=g_{t}$. In that respect our situation is di erent from tw o coupled $T$ om onaga-Luttinger mod-


FIG.8: O ccupation per site ( $n$ ) and di erence betw een the occupations of the two ferm ion species ( $n$ ) for the zig-zag chain. (100 sites per ferm ion species, PBC's, $=0,10^{4} \mathrm{M} \mathrm{C}$ sw eeps, $T=0: 1 t$.


FIG. 9: O ne of two possible ground state con gurations for the zig-zag $H$ am iltonian when $U \gg t$. The sites in the low er row are occupied by spin-up ferm ions, the sites in the upper row are empty. In the other ground state, the lower row is empty, and the upper completely led w ith (spin-down) ferm ions.
els as considered in Refs. Um klapp. The \absolute-drag" result of the form $g_{c}=g_{t}$ (e.g., from Ref. ${ }^{\prime}$ a spin-polarized interaction (see appendix).

If we assum e that a given potential is in general not spin dependent, the only relevant quantity is the fullconductance $g=2\left(g_{c}+g_{t}\right)$, which is only nonzero aw ay from half lling. H ere both spin orientations contribute equally to the current. H ow ever, the situation changes when we add a magnetic im purity. Even if the driving potential is still spin independent, the resulting current w ill be (partially) spin polarized, if we are aw ay from half lling. In the lim it of a large im purity potential the current $w$ ill be fully spin polarized.

APPENDIX A:SPIN-DEPENDENT
IN TERACTION| BROKENSPINTOTATIONAL INVARIANCE

In the $H$ ubbard $m$ odel $C$ is-and $T$ ransconductance have opposite sign, in sharp contrast to the bosonization results (for coupled spinless-ferm ion chains), where C isand $T$ ranscoductance are both positive. $T$ he discrepancy $m$ ay com $e$ from the di erent $m$ odeling of the interaction. In the bosonization approaches each chain is given by an
interacting system (i.e, the Luttinger-liquid param eter $K$ $m$ ay di er from one), in the $H$ ubbard $m$ odeleach spin sector alone is represented by a noninteracting ferm ion system. W ew ill.show in this appendix that a spin-polarized interaction leads to a positive T ransconductance as found in the bosonization approaches. To this end we w ill now discuss the follow ing variant of our H am iltonian:

$$
\begin{equation*}
\mathrm{H}=\mathrm{H}_{\mathrm{H} \text { ubb }}+\underset{\mathrm{n} ;}{\mathrm{X}} \mathrm{~J}_{\mathrm{z}}\left(\mathrm{n}_{\mathrm{n}} ; \quad 1=2\right)\left(\mathrm{n}_{\mathrm{n}+1 ;} \quad 1=2\right): \tag{A1}
\end{equation*}
$$

Here the new $J_{z}$ term breaks the spin-rotational invariance. H ence $K$ may now be di erent from one.

First we consider the large-U lim it at half lling. The $U$ term acts then as an e ective projection to the con gurations w ith exactly (because of half lling) one ferm ion
 fective (second-order perturbation theory) H am iltonian. From the kinetic-energy term we get again a H eisenberg $m$ odelw ith exchange param eter $4 t^{2}=U$. The $J_{z}$ term of the Ham iltonian does not change the con guration (in the occupation-num ber basis, and gives therefore a direct energy contribution $2 J_{z}{ }_{n} T_{n}^{z} T_{n+1}^{z}$ to the ective H am iltonian where $T_{n}^{z}=\left(n_{n} ;{ }^{\prime} \quad n_{n} ; \#\right)=2$ denotes the spin of the ferm ion on site $n$. The fulle ective H am iltonian reads

$$
\begin{aligned}
\mathrm{H}_{\mathrm{e}} & ={ }^{X}\left(4 t^{2}=U\right)\left(T_{n}^{+} T_{n+1}+T_{n+1}^{+} T_{n}\right)=2 \\
& +X^{n}\left(2 J_{z}+4 t^{2}=U\right) T_{n}^{z} T_{n+1}^{z} ;
\end{aligned}
$$

and is an $x x z$ chain. If the anisotropy is larger than the hopping am plitude, i.e., if $J_{z}>0$, this $m$ odel is gapped (im plying both a charge and a spin gap in the original m odel). W e therefore expect that C is-and T ransconductance go to zero, if we increase $U$ and keep a nite $J_{2}$.

N ow we consider a zero chem ical potential $=0 . \mathrm{We}$ expect that this chem ical potential shift aw ay from half
lling closes the charge gap, but leaves the spin gap m ore or less una ected. W e consider again the large-U lim it. In any con guration the $J_{z}$ term of the $H$ am iltonian gives the follow ing contribution for tw o neighboring sites

$$
\begin{aligned}
& J_{z}=2 \text { ifthe tw o sites are occupied w ith anti-parallelspins, } \\
& J_{z}=2 \text { if the tw o sites are occupied w ith parallel spins or } \\
& \text { are both em pty, }
\end{aligned}
$$

0 if one site is occupied and the other, not.
W e assum e that there is a spin gap and that the (degenerate) ground state con gurations are those forw hich the spins of the particles are ordered antiferrom agnetically. If only these con gurations are allow ed, the $J_{z}$ term can be represented as a one-site potentialw ith a contribution $J_{z}=2$ for em pty/occupied sites. (O ne obtains the sam e energy contributions as from the $J_{z}$ term of the original H am iltonian, if one keeps in $m$ ind that each site appears in precisely two pairs of neighboring sites.) W e can setup the follow ing e ective Ham iltonian (this is just the


FIG. 10: The same as Fig. . 140). The sim ulations aw ay from half lling su er from large autocorrelation tim es.
restriction of the original H am iltonian to the assum ed ground state con gurations, i.e., zeroth order in U )

$$
\mathrm{X}_{\mathrm{n}}\left[\left(\mathrm{R}_{\mathrm{n}}^{+} \mathrm{R}_{\mathrm{n}+1}+\mathrm{R}_{\mathrm{n}+1}^{+} \mathrm{R}_{\mathrm{n}}\right)=2+\mathrm{J}_{\mathrm{z}} \mathrm{R}_{\mathrm{n}}^{\mathrm{z}}\right] ;
$$

which is an $x x$ chain in $m$ agnetic eld, where the \spin" operator $R_{n}^{z}$ (this tim e denoted by $R$ to avoid confusion $w$ ith previous spin operators) is de ned by $R_{\mathrm{h}}^{\mathrm{z}}=1=2$ if there is a particle on site $n$ and $R_{n}^{z}=+1=2$ if site $n$ is empty. Since the e ective $H$ am iltonian describes the charge part of the $H$ am iltonian the full conductance $2\left(g_{c}+g_{t}\right)$ for the originalm odel should coincide $w$ ith the conductance of the new $H$ am, ittonian which is $\mathrm{e}^{2}=\mathrm{h}$ as the system is noninteracting ${ }^{104171}$. Since we have $g_{c}=g_{t}$ by the assum ption of a spin gap and Eq. ( $\mathbf{I}^{\prime}$ '), the relation $g=2\left(g_{c}+g_{t}\right)$ yields $g_{c}=0: 25 e^{2}=h=g_{t}$.

In principle the modelEq. (A Il ) can also be analyzed $w$ th the $M$ onte $C$ arlo $m$ ethod developed in this paper, but we found that the sim ulation for this case is problem atic: W e m easured large autocorrelation tim es for nite $J_{z}$ and (e.g., for the com putation of the com pressibil-斗y). W e therefore $m$ ust restrict ourselves to $J_{z} \quad 0: 8 t$.

For $J_{z}=0: 8 t$ we present results for the $C$ is and

Transconductance in Fig. 1 nd good agreem ent $w$ ith our prediction that $g=g_{t}=$ $0: 25 \mathrm{e}^{2}=\mathrm{h}$ which gives credit to the sim ulation data despite the large autocorrelation tim es.

H ere we want to stress once again the rem arkable fact that the sign of the Transconductance (the direction of the induced current) changes when we sw itch the magnetic eld and the spin-polarized interaction on. (T he Transconductance is for all U negative in $F$ ig. 12 in the present situation we expect $g_{t}=g_{c}=\bar{K}=2>0$ for $T=0 ; U=1$.)

O ccupation in the ground state| Sincewe identi ed the ground state of the H am iltonian Eq. (All) H ( $=0$; U !
1 ) w ith the ground state of the $x x$ chain in $m$ agnetic eld, we can calculate the occupation per state of this H am iltonian in the large U -lim it, the result being:

$$
\begin{aligned}
& \mathrm{X} \\
& \mathrm{n} ;
\end{aligned} \quad\left(\mathrm{n}_{\mathrm{n}} ;\right)=\mathrm{N}=1 \quad \arccos \left(\mathrm{~J}_{\mathrm{z}}=[2 \mathrm{t}]\right)=:
$$

This prediction $m$ ay be tested against a M onte C arlo sim ulation. We nd good agreem ent (see Fig in ì ).


FIG. 11: O ccupation per state (aw ay from half lling) for the $H$ am iltonian Eq. $\left(\mathbb{A} 1_{-1}^{1}\right) H(=0)$ for di erent $J_{z}$. The predicted high U values are given as dashed lines. (500 sites, PBC's, $10^{5} \mathrm{M}$ C sweeps, $T=0: 1 \mathrm{t}$.)
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